

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SZ07AFE

NON-Inverter (Open Drain)

Features

High output drive: ±24 mA (min)

at $V_{CC} = 3 V$

• Super high speed operation: t_{pZL} 2.3 ns (typ.)

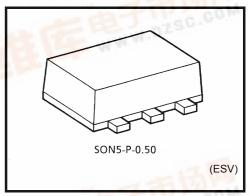
at $V_{CC} = 5 \text{ V}$, 50 pF

Operation voltage range: V_{CC (opr.)} = 1.65~5.5 V

5.5-V tolerant inputs

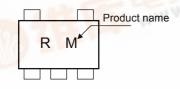
• 5.5-V power down protection outputs

 Matches the performance of TC74LCX series when operated at 3.3 -V V_{CC}

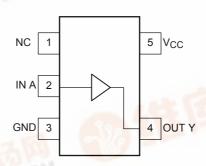


Weight: 0.003 g (typ.)

Marking



Pin Assignment (top view)



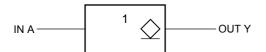
Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|------------------------------------|------------------|-----------------|------|
| Supply voltage range | V _{CC} | -0.5~6 | V |
| DC input voltage | V _{IN} | -0.5~6 | V |
| DC output voltage | V _{OUT} | −0.5~6 (Note 1) | V |
| Input diode current | l _{IK} | -20 | mA |
| Output diode current | lok | -20 (Note 2) | mA |
| DC output current | lout | 50 | mA |
| DC V _{CC} /ground current | I _{CC} | ±50 | mA |
| Power dissipation | P _D | 150 | mW |
| Storage temperature | T _{stg} | -65~150 | °C |
| Lead temperature (10 s) | TL | 260 | °C |

Note 1: I_{OUT} absolute maximum rating must be observed

Note 2: FVOUT < GND

Logic Diagram



Truth Table

| Α | Y |
|---|---|
| L | L |
| Н | Z |

Z: High impedance

Recommended Operating Conditions

| Characteristics | Symbol | Rating | Unit | | |
|--------------------------|--------------------------------|--|----------|--|--|
| Supply voltage | V _{CC} | 1.65~5.5 | V | | |
| Supply voltage | VCC. | 1.5~5.5 (Note 3) | v | | |
| Input voltage | V _{IN} | 0~5.5 | V | | |
| Output voltage | V _{OUT} | 0~V _{CC} | > | | |
| Operating temperature | T _{opr} | -40~85 | °C | | |
| | d _t /d _v | $0~20 \text{ (V}_{CC} = 1.8 \text{ V}, 2.5 \text{ V} \pm 0.2 \text{ V})$ | | | |
| Input rise and fall time | | $0\sim10~(V_{CC}=3.3~V\pm0.3~V)$ | ns/V | | |
| | | $0~5~(V_{CC} = 5.5~V \pm 0.5~V)$ | | | |

Note 3: Data retention only

Electrical Characteristics

DC Characteristics

| Characteristics Symbol Test Condition | | Symbol Tost Condition | | | Ta = 25°C | | | Ta = -40~85°C | | Unit | |
|---|-----------------|-----------------------|---|--------------------------|---------------------------|------|--------------------------|---------------------------|--------------------------|---------------------------|----|
| | | V _{CC} (V) | Min | Тур. | Max | Min | Max | Offic | | | |
| High level | V _{IH} | _ | | 1.65~1.95 | 0.75 × V _{CC} | | _ | 0.75 × V _{CC} | | V | |
| | VIН | | | 2.3~5.5 | 0.7 × V _{CC} | | _ | 0.7 × V _{CC} | | | |
| Input voltage | Low level | ., | | | 1.65~1.95 | | | 0.25 × V _{CC} | _ | 0.25 × V _{CC} | V |
| Low level | V _{IL} | | | 2.3~5.5 | | | 0.3 × V _{CC} | _ | 0.3 × V _{CC} | | |
| Z-state output leak | age current | lkg | V _{IN} = V _{IH} V _{OUT} = 0~5.5 V | | 1.65~5.5 | _ | _ | ±5 | _ | ±10 | μА |
| Output voltage Low level | | | | I _{OL} = 100 μA | 1.65 | _ | 0 | 0.1 | _ | 0.1 | - |
| | | | | | 2.3 | | 0 | 0.1 | _ | 0.1 | |
| | V _{OL} | $V_{IN} = V_{IL}$ | ΙΟΣ – 100 μΑ | 3.0 | _ | 0 | 0.1 | _ | 0.1 | V | |
| | | | | 4.5 | _ | 0 | 0.1 | _ | 0.1 | | |
| | | | I _{OL} = 8 mA | 2.3 | _ | 0.1 | 0.3 | _ | 0.3 | | |
| | | | I _{OL} = 16 mA | 3.0 | | 0.15 | 0.4 | _ | 0.4 | | |
| | | | I _{OL} = 24 mA | 3.0 | | 0.22 | 0.55 | _ | 0.55 | | |
| | | | $I_{OL} = 32 \text{ mA}$ | 4.5 | | 0.22 | 0.55 | _ | 0.55 | | |
| Input leakage current I_{IN} $V_{IN} = 5.5 \text{ V or GND}$ | | 0~5.5 | | | ±1 | _ | ±10 | μΑ | | | |
| Power off leakage current I_{OFF} V_{IN} or $V_{OUT} = 5.5 \text{ V}$ | | _T = 5.5 V | 0.0 | | | 1 | | 10 | μΑ | | |
| Quiescent supply current I_{CC} $V_{IN} = 5.5 \text{ V or GND}$ | | 5.5 | _ | _ | 2 | _ | 20 | μΑ | | | |

3

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

| Characteristics | Symbol | Test Condition | | Ta = 25°C | | | Ta = -40~85°C | | Unit |
|-------------------------------|------------------|-------------------------------------|---------------------|-----------|------|-----|---------------|------|-------|
| Characteristics Symi | | rest Condition | V _{CC} (V) | Min | Тур. | Max | Min | Max | Offic |
| | ^t pZL | C_L = 50 pF, R_L = 500 Ω | 1.8 ± 0.15 | 1.8 | 5.5 | 9.5 | 1.8 | 10.5 | |
| | | | 2.5 ± 0.2 | 1.2 | 3.7 | 5.8 | 1.2 | 6.4 | - ns |
| | | | 3.3 ± 0.3 | 0.8 | 2.9 | 4.4 | 0.8 | 4.8 | |
| Propagation delay time | | | 5.0 ± 0.5 | 0.5 | 2.3 | 3.5 | 0.5 | 3.9 | |
| | t _{pLZ} | C_L = 50 pF, R_L = 500 Ω | 1.8 ± 0.15 | 1.8 | 4.3 | 9.5 | 1.8 | 10.5 | |
| | | | 2.5 ± 0.2 | 1.2 | 2.8 | 5.8 | 1.2 | 6.4 | |
| | | | 3.3 ± 0.3 | 8.0 | 2.1 | 4.4 | 0.8 | 4.8 | |
| | | | 5.0 ± 0.5 | 0.5 | 1.4 | 3.5 | 0.5 | 3.9 | |
| Input capacitance | C _{IN} | | 0~5.5 | | 4 | _ | _ | _ | pF |
| Output capacitance | C _{OUT} | | 0~5.5 | | 8 | _ | | | pF |
| Power dissipation capacitance | C _{PD} | (Note 4) | 3.3 | _ | 20 | _ | | _ | pF |
| | | | 5.5 | _ | 26 | _ | | _ | рг |

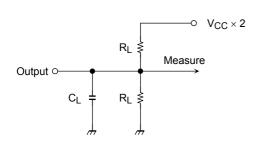
Note4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

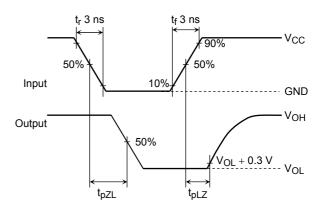
Average operating current can be obtained by the equation.

$$I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

AC Characteristics Measurement Circuit

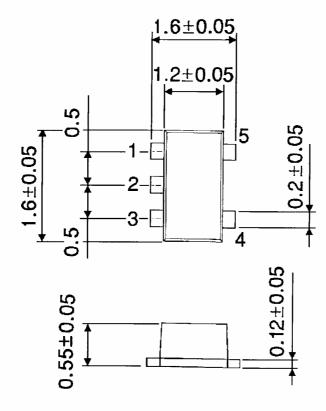
AC Waveforms





Package Dimensions

SON5-P-0.50 Unit: mm



Weight: 0.003 g (typ.)

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Handbook" etc..

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